

FJPF3305 High Voltage Switch Mode Application

- High Speed Switching
- Suitable for Electronic Ballast and Switching Regulator



Absolute Maximum Ratings * T_a = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	700	V
V _{CEO}	Collector-Emitter Voltage	400	V
V _{EBO}	Emitter-Base Voltage	9	V
I _C	Collector Current (DC)	4	A
I _{CP}	Collector Current (Pulse)	8	A
I _B	Base Current	2	A
P _C	Collector Dissipation ($T_a = 25^{\circ}C$)	30	W
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-65 ~ 150	°C

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

May 2007

Symbol	Parameter	Conditions	Min.	Тур.	Max	Units
BV _{CBO}	Collector-Base Breakdwon Voltage	$I_{C} = 500 \mu A, I_{E} = 0$	700			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 5 {\rm mA}, I_{\rm B} = 0$	400			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_{E} = 500 \mu A, I_{C} = 0$	9			V
I _{CBO}	Collector Cut-off Current	$V_{CB} = 700 V, I_E = 0$			1	μA
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 9V, I_{C} = 0$			1	μA
h _{FE1} h _{FE2}	DC Current Gain *	$V_{CE} = 5V, I_C = 1A$ $V_{CE} = 5V, I_C = 2A$	19 8		35 40	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_{C} = 1A, I_{B} = 0.2A$ $I_{C} = 2A, I_{B} = 0.5A$ $I_{C} = 4A, I_{B} = 1A$			0.5 0.6 1.0	V V V
V _{BE(sat)}	Base-Emitter Saturation Voltage	$I_{C} = 1A, I_{B} = 0.2A$ $I_{C} = 2A, I_{B} = 0.5A$			1.2 1.6	V V
f _T	Current Gain Bandwidth Product	$V_{CE} = 5V, I_{C} = 1A$	4			MHz
C _{ob}	Output Capacitance	V _{CB} = 10V, f = 1MHz		65		pF
t _{ON}	Turn On Time	V _{CC} = 125V			0.8	μS
t _{STG}	Storge Time	$I_{\rm C} = 2A = 5I_{\rm B1} = -5I_{\rm B2}$			4.0	μS
t _F	Fall Time	$-R_{L} = 62.5\Omega$			0.9	μS

atrical Characteristics

* Pulse Test: PW $\leq 300 \mu s,$ Duty Cycle $\leq 2\%$

h_{FE} Classification

Classification	H1	H2
h _{FE2}	19 ~ 28	26 ~ 35

Typical Performance Characteristics

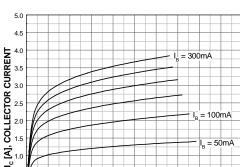


Figure 1. Static Characteristic

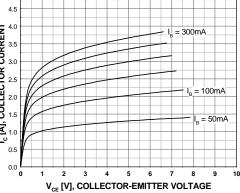


Figure 3. DC Current Gain (O-Grade)

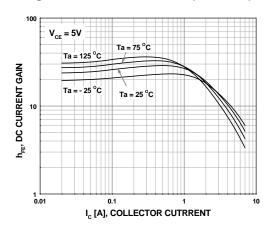


Figure 5. Saturatin Voltage (O-Grade)

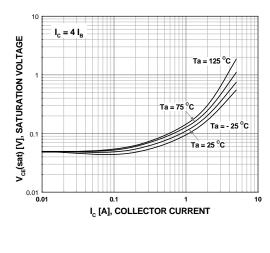


Figure 2. DC Current Gain (R-Grade)

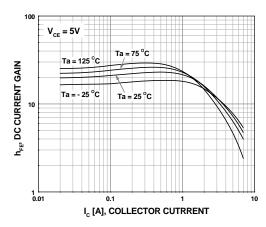


Figure 4. Saturation Voltage (R-Grade)

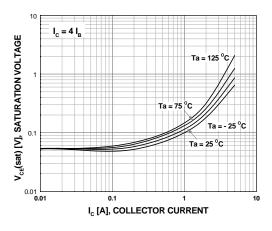
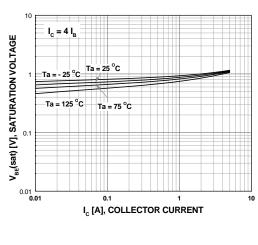
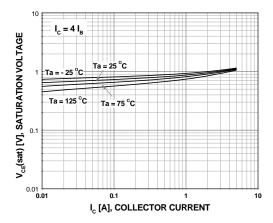


Figure 6. Saturation Voltage (R-Grade)

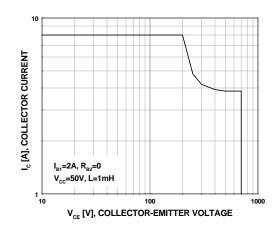


Typical Performance Characteristics (Continued)

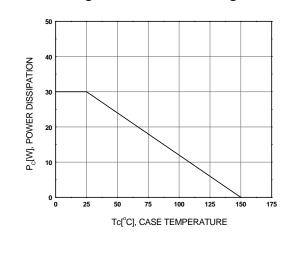
Figure 7. Saturation Voltage (O-Grade)

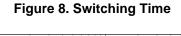


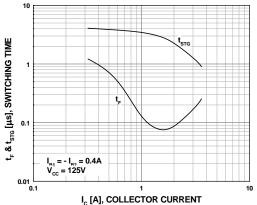


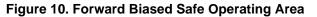


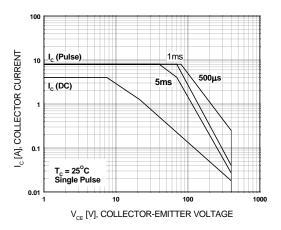


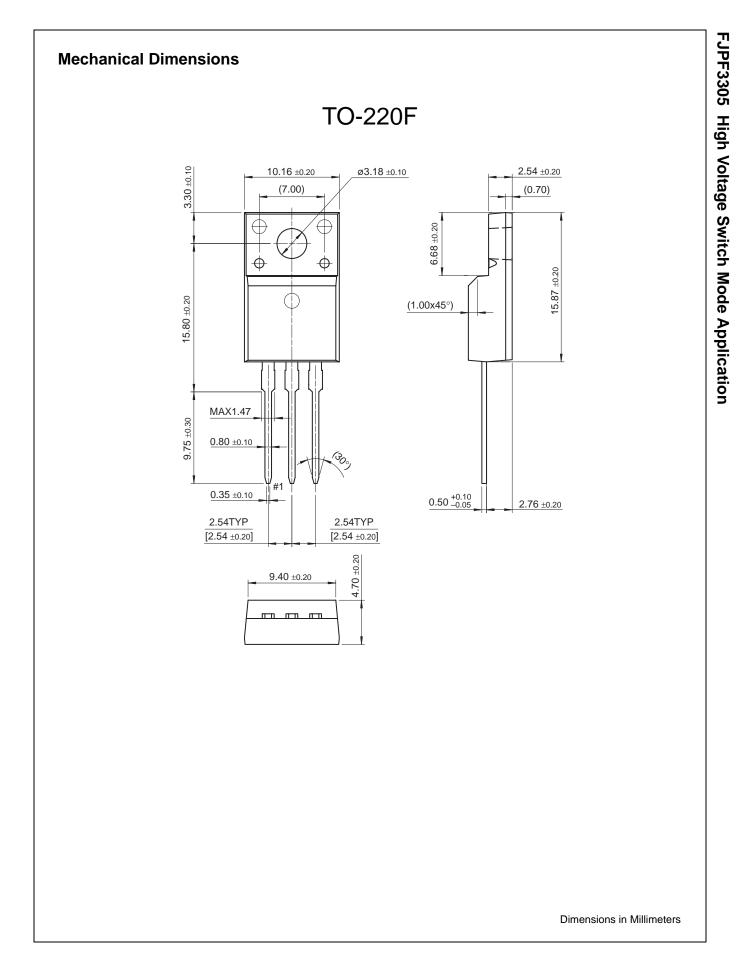














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